1. Record Nr. UNINA9910784355703321 Autore Grebennikov Andrei <1956-> Titolo Switchmode RF power amplifiers [[electronic resource] /] / Andrei Grebennikov and Nathan O. Sokal Burlington, MA;; Amsterdam,: Elsevier/Newnes, c2007 Pubbl/distr/stampa **ISBN** 1-281-05762-2 9786611057626 0-08-055064-9 Descrizione fisica 1 online resource (443 p.) Collana Communications engineering series Switchmode RF power amplifiers Altri autori (Persone) SokalNathan O Disciplina 621.381535 Soggetti Power amplifiers Microwave amplifiers Lingua di pubblicazione Inglese **Formato** Materiale a stampa Livello bibliografico Monografia Note generali Description based upon print version of record. Nota di bibliografia Includes bibliographical references and index. Nota di contenuto Front Cover; Switchmode RF Power Amplifiers; Copyright Page; Table of Contents; About Andrei Grebennikov; About Nathan O. Sokal; Preface; Acknowledgments; Chapter 1: Power-Amplifier Design Principles; 1.1 Spectral-Domain Analysis; 1.2 Basic Classes of Operation: A, AB, B, and C; 1.4 High-Frequency Conduction Angle; 1.5 Nonlinear Effect of Collector Capacitance: 1.6 Push-Pull Power Amplifiers: References: Chapter 2: Class-D Power Amplifiers; 2.1 Switched-Mode Power Amplifiers with Resistive Load; 2.2 Complementary Voltage-Switching Configuration 2.3 Transformer-Coupled Voltage-Switching Configuration 2.4 Symmetrical Current-Switching Configuration; 2.5 Transformer-Coupled Current-Switching Configuration; 2.6 Voltage-Switching Configuration with Reactive Load: Chapter 3: Class-F Power Amplifiers: 3.1 Biharmonic Operation Mode; 3.6 Load Networks with Lumped Elements; Chapter 4: Inverse Class F; 4.1 Biharmonic Operation Mode; 4.4 Load Networks with Lumped Elements; References; Chapter 5: Class E with Shunt Capacitance; 5.1 Effect of Detuned Resonant Circuit; 5.2 Load Network with Shunt Capacitor and Series Filter 5.3 Matching with Standard Load5.8 Load Network with Transmission Lines: 5.9 Practical RF and Microwave Class-E Power Amplifiers and

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Sommario/riassunto

A majority of people now have a digital mobile device whether it be a cell phone, laptop, or blackberry. Now that we have the mobility we want it to be more versatile and dependable; RF power amplifiers accomplish just that. These amplifiers take a small input and make it stronger and larger creating a wider area of use with a more robust signal. Switching mode RF amplifiers have been theoretically possible for decades, but were largely impractical because they distort analog signals until they are unrecognizable. However, distortion is not an issue with digital signals-like those used